

International IOR Rectifier

IRKU/V105 SERIES

THYRISTOR/ THYRISTOR

ADD-A-pak™ GEN V Power Modules

Features

- High Voltage
- Industrial Standard Package
- Thick Al metal die and double stick bonding
- Thick copper baseplate
- UL E78996 approved
- 3500V_{RMS} isolating voltage

Benefits

- Up to 1600V
- Full compatible TO-240AA
- High Surge capability
- Easy Mounting on heatsink
- Al₂O₃ DBC insulator
- Heatsink grounded

105 A

Mechanical Description

The Generation V of Add-A-pak module combine the excellent thermal performance obtained by the usage of Direct Bonded Copper substrate with superior mechanical ruggedness, thanks to the insertion of a solid Copper baseplate at the bottom side of the device. The Cu baseplate allow an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improve thermal spread. The Generation V of AAP module is manufactured without hard mold, eliminating in this way any possible direct stress on the leads.

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other IR modules.

Electrical Description

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

Major Ratings and Characteristics

Parameters	IRKU/V105	Units
$I_{T(AV)}$ @ 85°C	105	A
$I_{T(RMS)}$	165	A
I_{TSM} @ 50Hz	1785	A
@ 60Hz	1870	A
I^2t @ 50Hz	15.91	KA ² s
@ 60Hz	14.52	KA ² s
$I^2\sqrt{t}$	159.1	KA ² √s
V_{RRM} range	400 to 1600	V
T_{STG}	-40 to 125	°C
T_J	-40 to 130	°C



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Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak reverse voltage V	V_{DRM} , max. repetitive peak off-state voltage, gate open circuit V	I_{RRM} I_{DRM} 130°C mA
IRKU/V105	04	400	500	400	20
	08	800	900	800	
	12	1200	1300	1200	
	16	1600	1700	1600	

On-state Conduction

Parameters	IRKU/V105	Units	Conditions
$I_{T(AV)}$ Max. average on-state current	105	A	180° conduction, half sine wave, $T_C = 85^\circ\text{C}$
$I_{T(RMS)}$ Max. RMS on-state current. @ T_C	165	°C	DC
	77		
I_{TSM} Max. peak, one cycle non-repetitive on-state current	1785	A	t=10ms No voltage
	1870		t=8.3ms reappplied
	1500		t=10ms 100% V_{RRM}
	1570		t=8.3ms reappplied
	2000		t=10ms $T_J = 25^\circ\text{C}$,
	2100		t=8.3ms no voltage reappplied
I^2t Max. I^2t for fusing	15.91	KA ² s	t=10ms No voltage
	14.52		t=8.3ms reappplied
	11.25		t=10ms 100% V_{RRM}
	10.27		t=8.3ms reappplied
	20.00		t=10ms $T_J = 25^\circ\text{C}$,
	18.30		t=8.3ms no voltage reappplied
I^2vt Max. I^2vt for fusing (1)	159.1	KA ² /s	t=0.1 to 10ms, no voltage reappl., $T_J = T_J \text{ max.}$
$V_{T(TO)}$ Max. value of threshold voltage (2)	0.80	V	Low level (3)
	0.85		High level (4)
r_t Max. value of on-state slope resistance (2)	2.37	mΩ	Low level (3)
	2.25		High level (4)
V_{TM} Max. peak on-state voltage	1.64	V	$I_{TM} = \pi \times I_{T(AV)}$
			$I_{FM} = \pi \times I_{F(AV)}$
di/dt Max. non-repetitive rate of rise of turned on current	150	A/μs	$T_J = 25^\circ\text{C}$, from 0.67 V_{DRM} , $I_{TM} = \pi \times I_{T(AV)}$, $I_g = 500\text{mA}$, $t_r < 0.5 \mu\text{s}$, $t_p > 6 \mu\text{s}$
I_H Max. holding current	200	mA	$T_J = 25^\circ\text{C}$, anode supply = 6V, resistive load, gate open circuit
I_L Max. latching current	400		$T_J = 25^\circ\text{C}$, anode supply = 6V, resistive load

(1) I^2t for time $t_x = I^2 \sqrt{t} \times \sqrt{t_x}$

(2) Average power = $V_{T(TO)} \times I_{T(AV)} + r_t \times (I_{T(RMS)})^2$

(3) $16.7\% \times \pi \times I_{AV} < I < \pi \times I_{AV}$

(4) $I > \pi \times I_{AV}$

Triggering

Parameters	IRK.U/V105	Units	Conditions	
P_{GM} Max. peak gate power	12	W		
$P_{G(AV)}$ Max. average gate power	3			
I_{GM} Max. peak gate current	3	A		
$-V_{GM}$ Max. peak negative gate voltage	10	V	Anode supply = 6V resistive load	
V_{GT} Max. gate voltage required to trigger	4.0			$T_J = -40^\circ\text{C}$
	2.5			$T_J = 25^\circ\text{C}$
	1.7	$T_J = 125^\circ\text{C}$		
I_{GT} Max. gate current required to trigger	270	mA	Anode supply = 6V resistive load	
	150			$T_J = -40^\circ\text{C}$
	80			$T_J = 125^\circ\text{C}$
V_{GD} Max. gate voltage that will not trigger	0.25	V	$T_J = 125^\circ\text{C}$, rated V_{DRM} applied	
I_{GD} Max. gate current that will not trigger	6	mA	$T_J = 125^\circ\text{C}$, rated V_{DRM} applied	

Blocking

Parameters	IRKU/V105	Units	Conditions
I_{RRM} Max. peak reverse and I_{DRM} off-state leakage current at V_{RRM} , V_{DRM}	20	mA	$T_J = 130^\circ\text{C}$, gate open circuit
V_{INS} RMS isolation voltage	2500 (1 min) 3500 (1 sec)	V	50 Hz, circuit to base, all terminals shorted
dv/dt Max. critical rate of rise of off-state voltage (5)	500	V/ μs	$T_J = 130^\circ\text{C}$, linear to $0.67 V_{DRM}$, gate open circuit

(5) Available with $dv/dt = 1000\text{V}/\mu\text{s}$, to complete code add S90 i.e. IRKU105/16AS90.**Thermal and Mechanical Specifications**

Parameters	IRKU/V105	Units	Conditions
T_J Junction operating temperature range	-40 to 130	$^\circ\text{C}$	
T_{stg} Storage temperature range	-40 to 125		
R_{thJC} Max. internal thermal resistance, junction to case	0.135	K/W	Per module, DC operation
R_{thCS} Typical thermal resistance case to heatsink	0.1		Mounting surface flat, smooth and greased
T Mounting torque $\pm 10\%$ to heatsink busbar	5	Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound
	3		
wt Approximate weight	110 (4)	g (oz)	
Case style	TO-240AA		JEDEC

 ΔR Conduction (per Junction)(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sine half wave conduction					Rect. wave conduction					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRKU/V105	0.04	0.05	0.06	0.08	0.12	0.03	0.05	0.06	0.08	0.12	$^\circ\text{C}/\text{W}$

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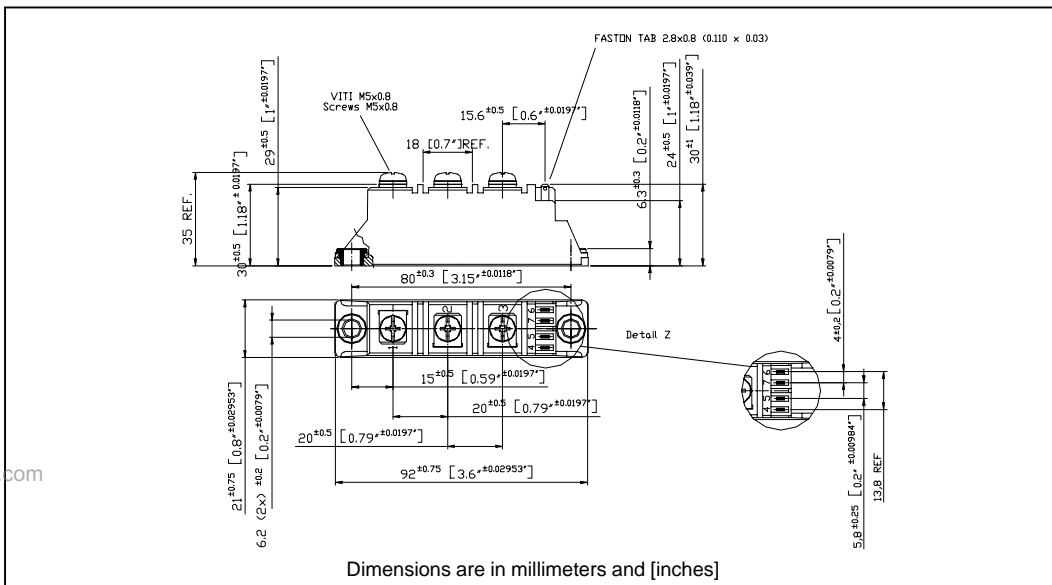
Ordering Information Table

Device Code					
IRK	U	105	/	16	A S90
①	②	③		④	⑤ ⑥

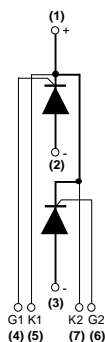
<p>1 - Module type</p> <p>2 - Circuit configuration (See Circuit Configuration table below)</p> <p>3 - Current code **</p> <p>4 - Voltage code (See Voltage Ratings table)</p> <p>5 - A : Gen V</p> <p>6 - dv/dt code: S90 = dv/dt 1000 V/μs No letter = dv/dt 500 Vμs</p>	<p>** Available with no auxiliary cathode. To specify change: 105 to 106</p> <p>e.g. : IRKU106/16A etc.</p>
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IRK.106 types
With no auxiliary cathode

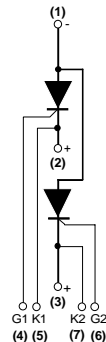
Outline Table



IRKU



IRKV



NOTE: To order the Optional Hardware see Bulletin I27900

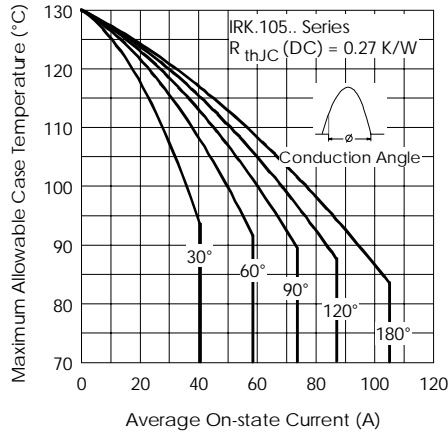


Fig. 1 - Current Ratings Characteristics

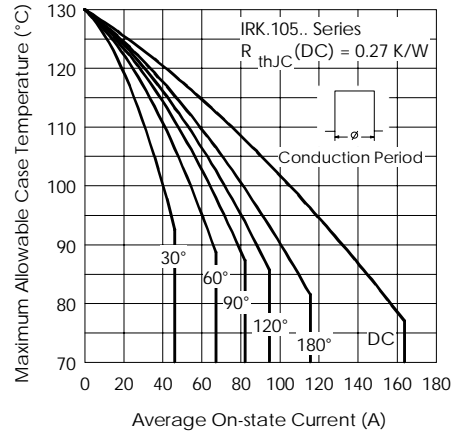


Fig. 2 - Current Ratings Characteristics

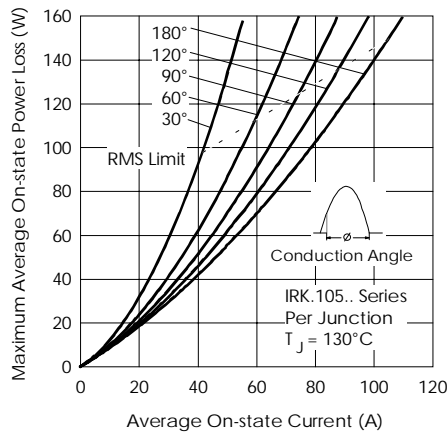


Fig. 3 - On-state Power Loss Characteristics

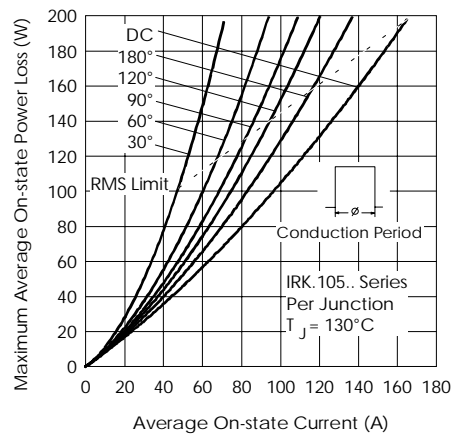


Fig. 4 - On-state Power Loss Characteristics

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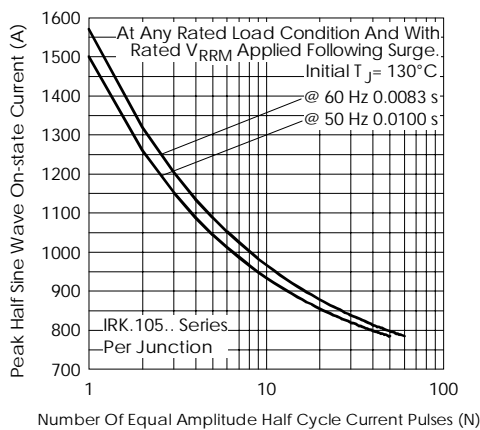


Fig. 5 - Maximum Non-Repetitive Surge Current

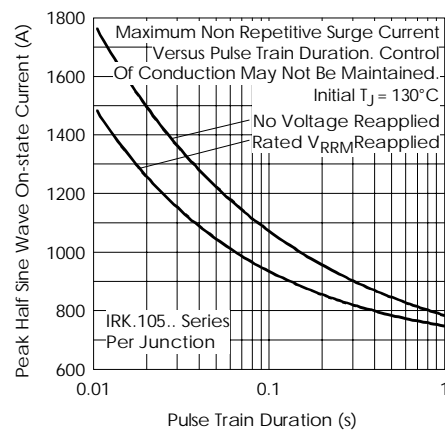


Fig. 6 - Maximum Non-Repetitive Surge Current

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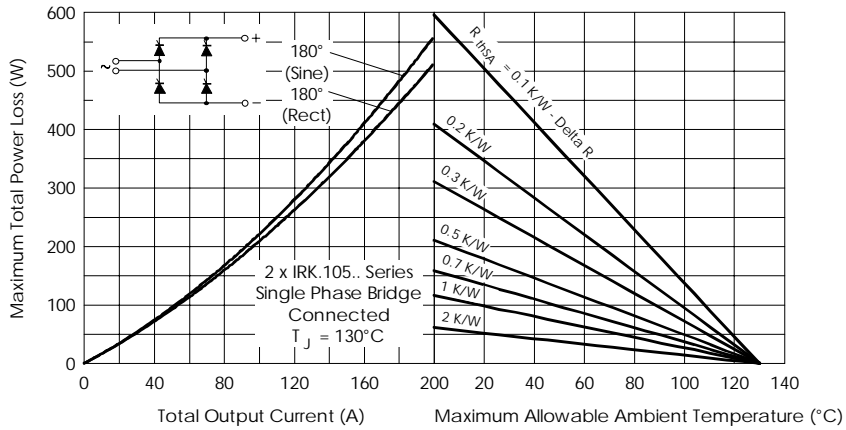


Fig. 7 - On-state Power Loss Characteristics (Single Phase Bridge IRKU+IRKV)

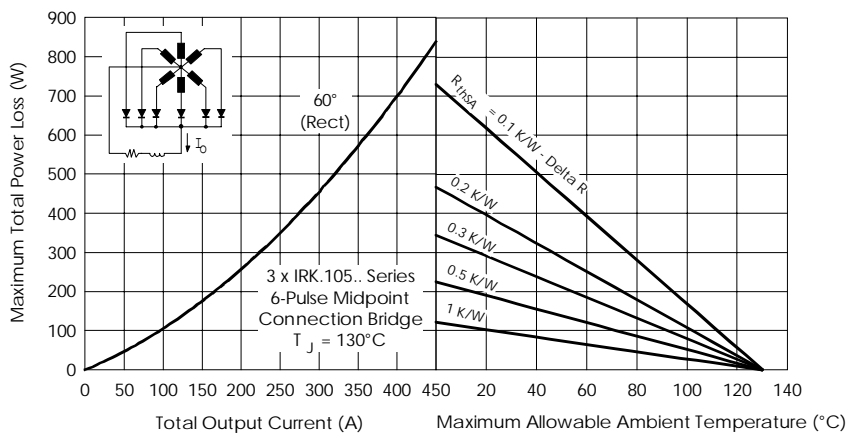


Fig. 8 - On-state Power Loss Characteristics

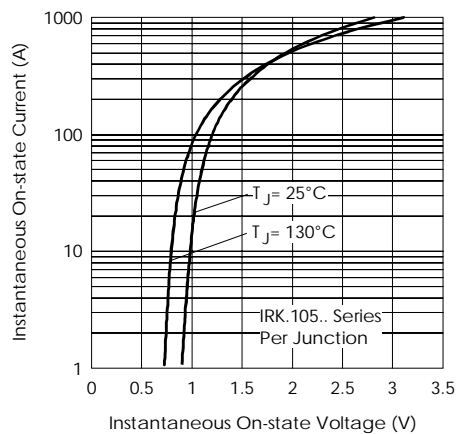


Fig. 9 - On-state Voltage Drop Characteristics

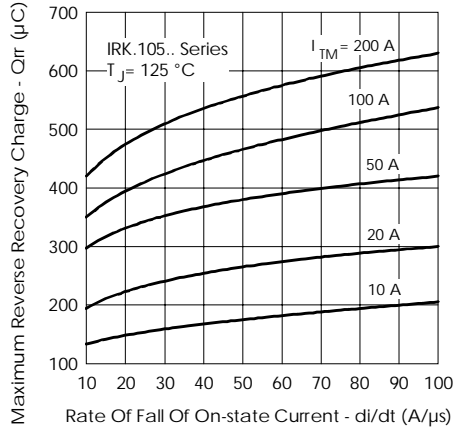


Fig. 10 - Recovery Charge Characteristics

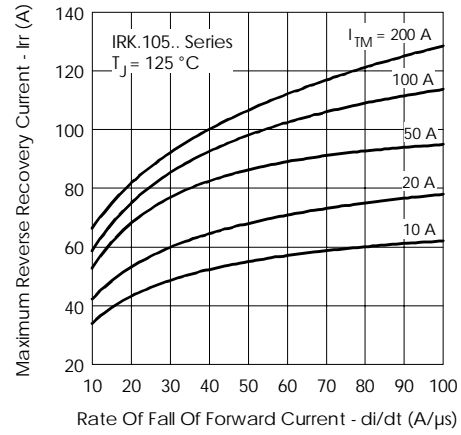


Fig. 11 - Recovery Current Characteristics

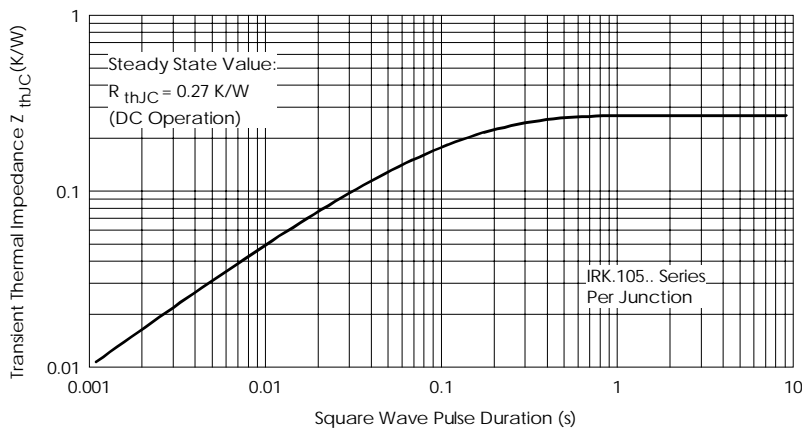


Fig. 12 - Thermal Impedance Z_{thJC} Characteristics

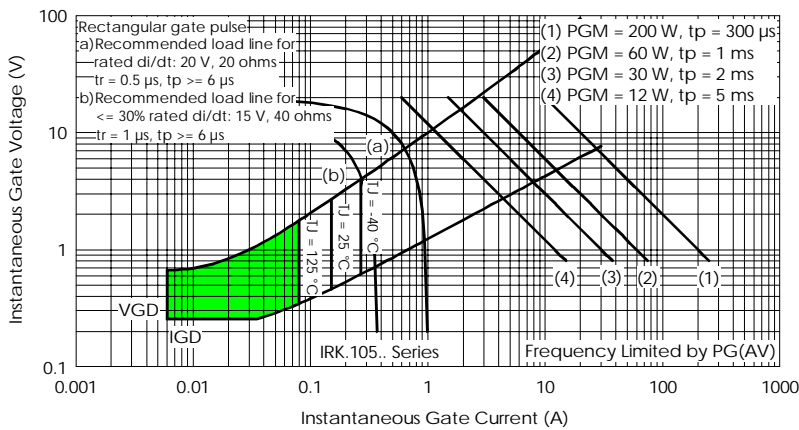


Fig. 13- Gate Characteristics

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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